

## HMIC™ PIN Diode SP2T 8 Watt Switch for 0.05 - 6.0 GHz Higher Power Applications

M/A-COM Products  
Rev 3

### Features

- Exceptional Broadband Performance, 0.05 - 6.0 GHz
- Lower Loss: Tx = 0.35 dB, Rx = 0.55 dB @ 3.8 GHz, 20mA
- Higher Isolation: Rx-Tx = 21dB, Tx-Rx = 26dB @ 3.8 GHz
- Higher RF Input Power = 8 W C.W ( Tx-Ant Port )
- Higher IIP3 = 65 dBm ( Tx-Ant Port ).
- Lower EVM (OFDM): < 1.0% @ 8W Pinc, ( Tx-Ant Port )
- Suitable for Higher Power WiMAX & WiFi Applications
- Surface Mount 3mm MLP Package, RoHS\* Compliant

### Description and Applications

The MA-COM MASW-000822-12770T is a SP2T Broadband, high linearity, common anode, PIN diode T/R switch for

0.05 - 6.0 GHz applications, including WiMAX & WiFi. The device is provided in industry standard 3mm MLP plastic packaging. This device incorporates a PIN diode die fabricated with M/A-COM's patented Silicon-Glass HMIC™ process. This chip features two silicon pedestals embedded in a low loss, low dispersion glass. The diodes are formed on the top of each pedestal. The topside is fully encapsulated with silicon nitride and has an additional polymer passivation layer. These polymer protective coatings prevent damage and contamination during handling and assembly.

This compact 3mm MLP package, SP2T switch offers wideband 0.05 - 6.0 GHz performance with excellent isolation to loss ratio for both Tx and Rx states. The PIN diode provides exceptional 8 W C.W. power handling coupled with 65 dBm IIP3 for maximum switch performance.

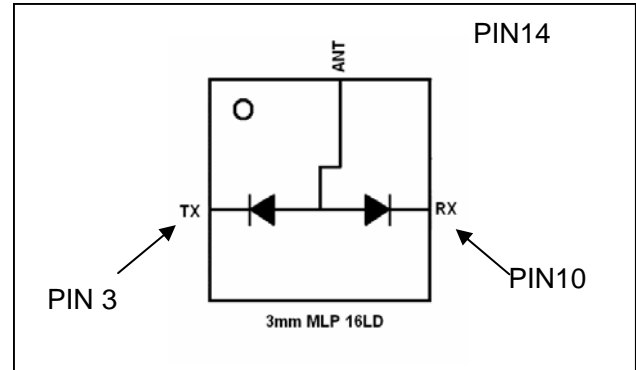
### Absolute Maximum Ratings <sup>1</sup>

@ T<sub>A</sub> = +25 °C (unless otherwise specified)

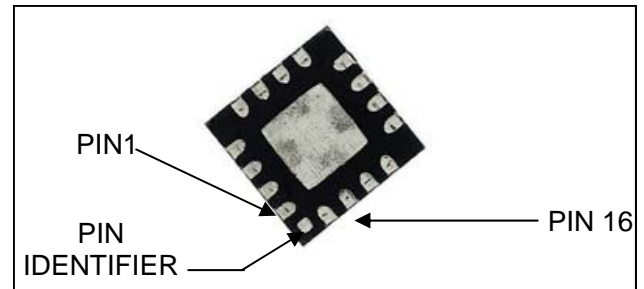
Parameter	Absolute Maximum
Forward Current	100 mA
Reverse Voltage ( RF & D.C. )	-100 V
Operating Temperature	-40 °C to +85 °C
Storage Temperature	-55 °C to +150 °C
Junction Temperature	+175 °C
Tx Incident C.W. Power	8 W C.W.
Tx Peak Incident Power	20 W, 3 uS P.W., 1% Duty
Mounting Temperature	+235 °C for 10 seconds

1. Exceeding these limits may cause permanent damage.

### Functional Diagram (TOP VIEW)



### Circuit Side View



### PIN Configuration:

(Center Metal Area is RF, D.C., and Thermal Ground)

PIN	Function	PIN	Function
1	N/C	9	N/C
2	N/C	10	Rx
3	Tx	11	N/C
4	N/C	12	N/C
5	N/C	13	N/C
6	N/C	14	Ant
7	N/C	15	N/C
8	N/C	16	N/C

### Ordering Information

Part Number	Package
MASW-000822-12770T	Tape and Reel

\* Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

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## Electrical Specifications at +25°C, Characteristic Impedance, $Z_0 = 50 \Omega$

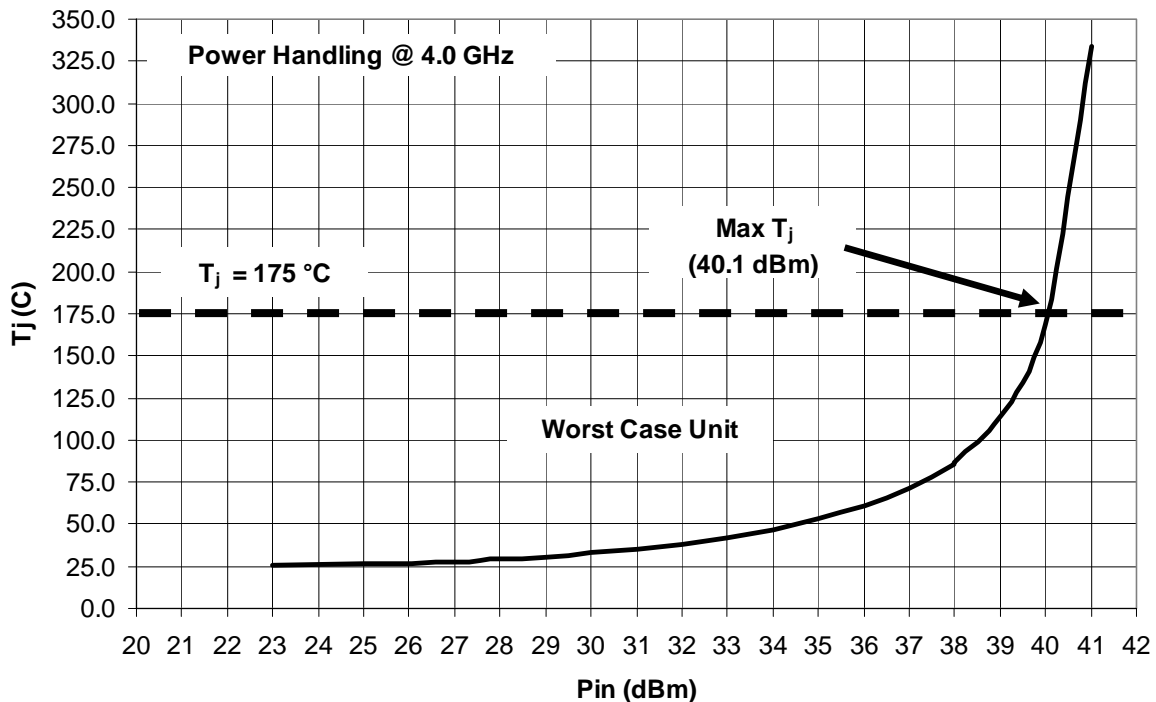
Parameter	Symbol	Conditions	Units	Min	Typ	Max
<b>F = 2.3-2.7 GHz</b>						
Insertion Loss, Rx	Rx IL	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB		0.52	0.70
Insertion Loss, Tx	Tx IL	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB		0.35	0.45
Isolation, Tx To Rx	Rx ISO	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB	27.0	29.5	
Isolation, Rx To Tx	Tx ISO	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB	22.5	24.5	
Tx Input Return Loss	Tx RL	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB		17	
Rx Input Return Loss	Rx RL	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB		17	
<b>F = 3.3-3.8 GHz</b>						
Insertion Loss, Rx	Rx IL	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB		0.55	0.75
Insertion Loss, Tx	Tx IL	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB		0.35	0.55
Isolation, Tx To Rx	Rx ISO	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB	24.5	26.5	
Isolation, Rx To Tx	Tx ISO	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB	19.5	21.5	
Tx Input Return Loss	Tx RL	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB		18	
Input Return Loss	Rx RL	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB		18	
<b>F = 4.9-5.9 GHz</b>						
Insertion Loss, Rx	Rx IL	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB		0.65	1.00
Insertion Loss, Tx	Tx IL	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB		0.4	0.85
Isolation, Tx To Rx	Rx ISO	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB	23.0	25.5	
Isolation, Rx To Tx	Tx ISO	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB	17.5	20.0	
Tx Input Return Loss	Tx RL	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA, Pinc= 0 dBm	dB		18	
Rx Input Return Loss	Rx RL	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA, Pinc= 0 dBm	dB		18	

## ESD Rating : These devices are rated at Class 1B Human Body

**Electrical Specifications at +25°C, Characteristic Impedance, Zo = 50 Ω**

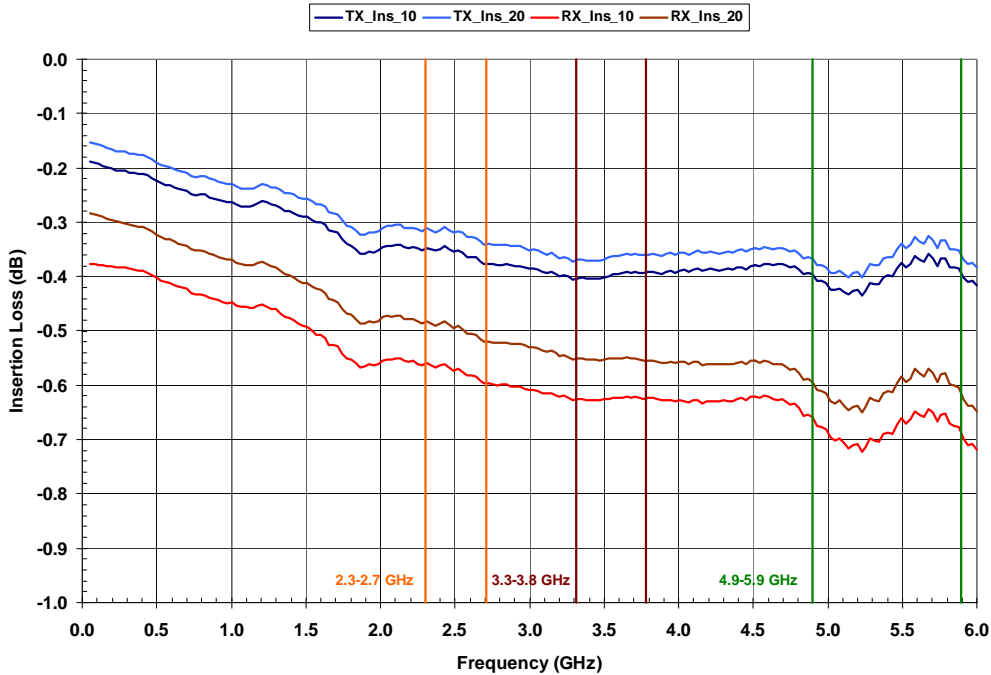
Parameter	Symbol	Conditions	Units	Min	Typ	Max
Tx Input P0.2dB	Tx IP0.2dB	3.5 GHz, Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA Tx To Antenna	dBm		36	
Tx Input P1dB	Tx IP1dB	3.5 GHz, Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA Tx To Antenna	dBm		40	
Tx 2 <sup>nd</sup> Harmonic	Tx 2Fo	3.5 GHz, Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA Pin = + 30 dBm	dBc		68	
Tx 3 <sup>rd</sup> Harmonic	Tx 3Fo	3.5 GHz, Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA Pin = + 30 dBm	dBc		84	
Tx Input Third Order Intercept Point	Tx IIP3	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA Pi= +10dBm, F1 = 3.500 GHz, F2 = 3.510 GHz	dBm		65	
Tx C.W. Input Power	Tx Pinc	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA F = 3.5 GHz	dBm			39
Rx C.W. Input Power	Rx Pinc	Rx = +5.0 V@ +22mA, Tx =+12V @ 0mA F = 3.5 GHz	dBm			33
Tx RF Switching Speed	τ <sub>RF</sub>	( 10-90% RF Voltage) Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA 1MHz Rep Rate in Modulating Mode	us		1	
Tx EVM (OFDM)	EVM	Tx = +5.0 V@ +22mA, Rx =+12V @ 0mA Pinc = +39 dBm	%		0.8	

**Tx Diode Junction Temperature vs. C.W. Input Power**



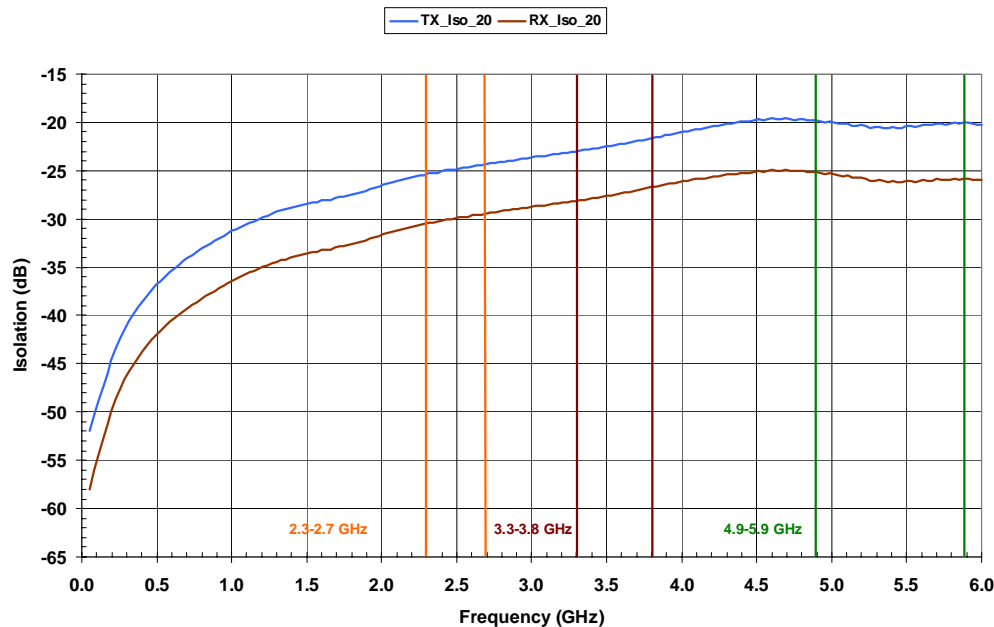
## MASW-000822-12770T Typical Performance Curves @ +25°C

*Tx & Rx Insertion Loss Bias Conditions: 10 mA and 20 mA for Low Loss , 11 V Back Bias for Isolation*



*Tx & Rx Isolation 20 mA for Loss, 11 V Back Bias for Isolation*

MASW-000822-12770T, Tx & Rx Isolation, 25C



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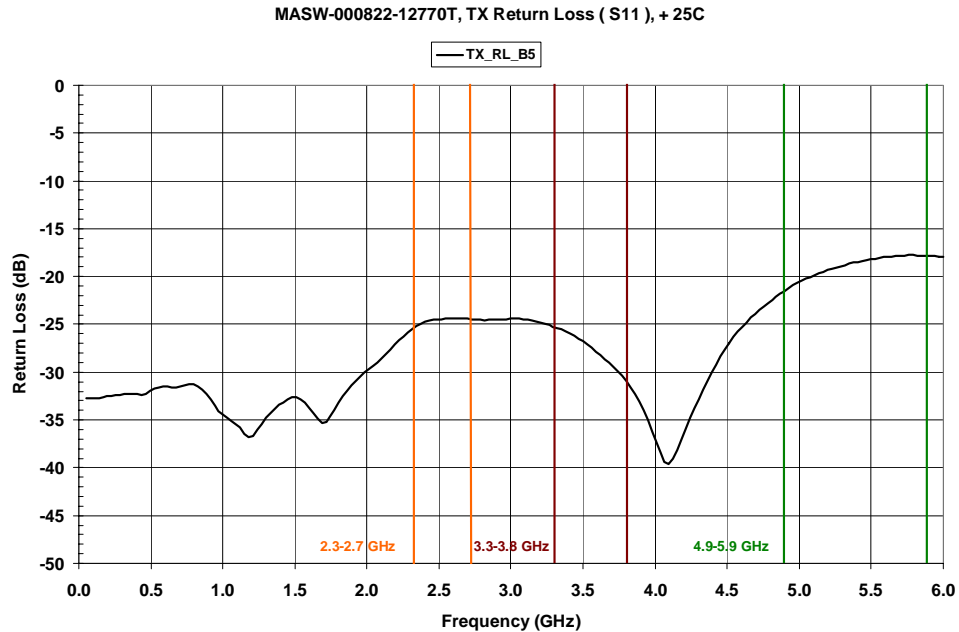
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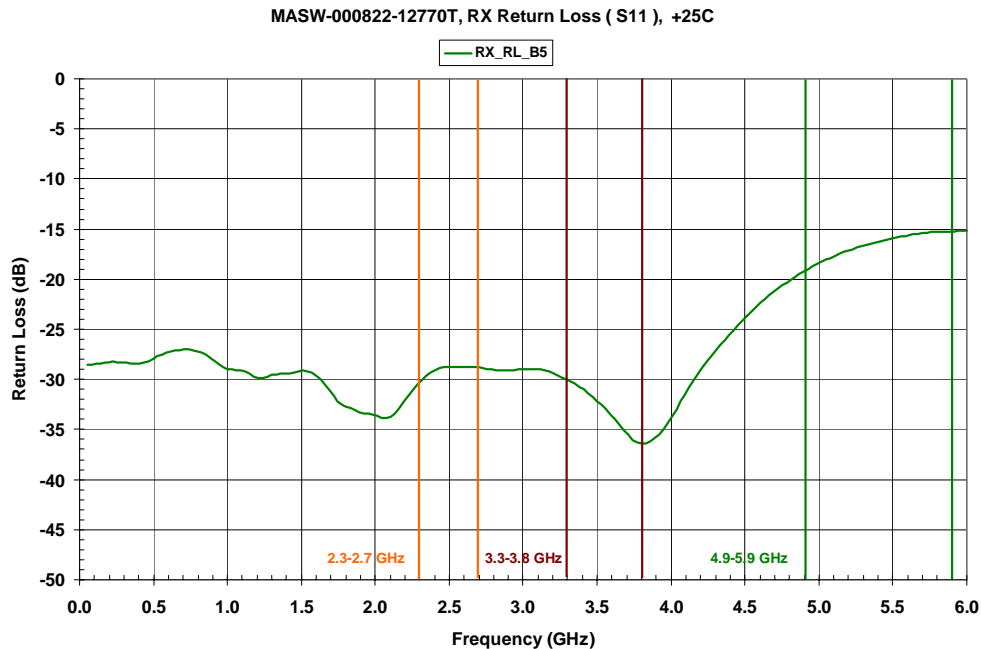
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## MASW-000822-12770T Typical Performance Curves @ +25°C

*Tx Return Loss 20 mA for Loss, 11 V Back Bias for Isolation*



*Rx Return Loss 20 mA for Loss, 11 V Back Bias for Isolation*





## MASW-000822-12770T Outline – 3mm FQFP-N 16 Lead Saw Singulated

